NSN 5962-01-146-1327

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-146-1327 **Body Length:** 0.808 inches **Body Width:** 0.257 inches **Body Height:** 0.204 inches **Maximum Power Dissipation Rating:** 800.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Cp-1418/tps 97942 **Features Provided:** Bipolar and 3-state output and w/enable and w/buffered output and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Demilitarization:

Yes - demil/mli

Unit Of Measure:

NSN 5962-01-146-1327

Memory Microcircuit - Page 2 of 2



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